

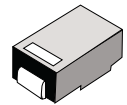
**Surface Mount  
Schottky Barrier Rectifiers**

Using the Schottky Barrier principle with a Molybdenum barrier metal. These state-of-the-art geometry features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency rectification, or as free wheeling and polarity protection diodes, in surface mount applications where compact size and weight are critical to the system.

- \* Low Forward Voltage.
- \* Low Switching noise.
- \* High Current Capacity
- \* Guarantee Reverse Avalanche.
- \* Guard-Ring for Stress Protection.
- \* Low Power Loss & High efficiency.
- \* 125 °C Operating Junction Temperature
- \* Low Stored Charge Majority Carrier Conduction.
- \* Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

**SCHOTTKY BARRIER  
RECTIFIERS**

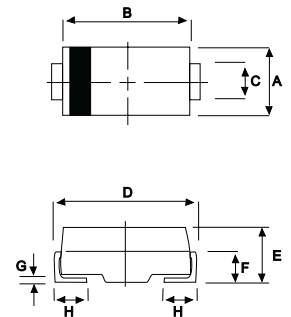
**1.0 AMPERES  
20-40 VOLTS**



**DO-214AC(SMA)**

**MAXIMUM RATINGS**

| Characteristic   | Symbol                          | SM17          | SM18 | SM19 | Unit |
|--|---------------------------------|---------------|------|------|------|
| Peak Repetitive Reverse Voltage<br>Working Peak Reverse Voltage<br>DC Blocking Voltage                         | $V_{RRM}$<br>$V_{RWM}$<br>$V_R$ | 20            | 30   | 40   | V    |
| RMS Reverse Voltage  | $V_{R(RMS)}$                    | 14            | 21   | 28   | V    |
| Average Rectifier Forward Current  | $I_O$                           | 1.0           |      |      | A    |
| Non-Repetitive Peak Surge Current<br>( Surge applied at rate load conditions<br>halfwave, single phase, 60Hz ) | $I_{FSM}$                       | 25            |      |      | A    |
| Operating and Storage Junction<br>Temperature Range  | $T_J, T_{stg}$                  | - 65 to + 125 |      |      | °C   |



| DIM | MILLMETERS |      |
|-----|------------|------|
|     | MIN        | MAX  |
| A   | 2.20       | 2.80 |
| B   | 4.10       | 4.70 |
| C   | 1.30       | 1.70 |
| D   | 4.60       | 5.30 |
| E   | 1.90       | 2.50 |
| F   | ---        | 1.30 |
| G   | ---        | 0.22 |
| H   | 0.85       | 1.45 |

**ELECTRICAL CHARACTERISTICS**

| Characteristic   | Symbol | SM17           | SM18           | SM19           | Unit |
|--|--------|----------------|----------------|----------------|------|
| Maximum Instantaneous Forward Voltage<br>( $I_F=1.0$ Amp )<br>( $I_F=3.0$ Amp )                                      | $V_F$  | 0.450<br>0.750 | 0.550<br>0.875 | 0.600<br>0.900 | V    |
| Maximum Instantaneous Reverse Current<br>( Rated DC Voltage, $T_c = 25$ °C )<br>( Rated DC Voltage, $T_c = 100$ °C ) | $I_R$  | 1.0<br>20      |                |                | mA   |
| Typical Junction Capacitance<br>( Reverse Voltage of 4 volts & $f=1$ MHz )   | $C_P$  | 85             | 75             |                | pF   |

CASE---  
Transfer molded  
plastic

POLARITY---  
Cathode indicated  
polarity band

FIG-1 FORWARD CURRENT DERATING CURVE

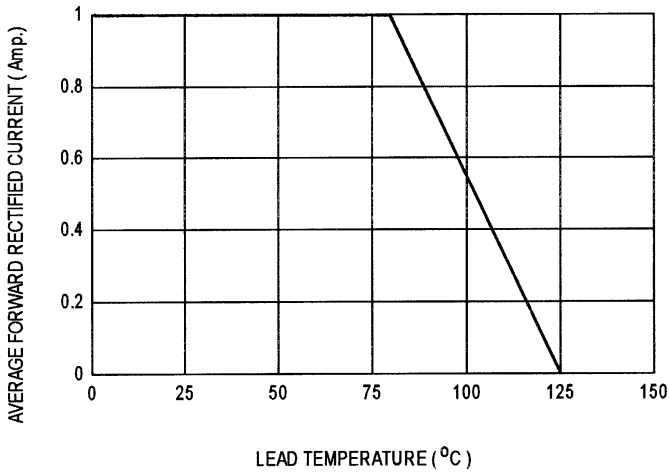


FIG-2 TYPICAL FORWARD CHARACTERISTICS

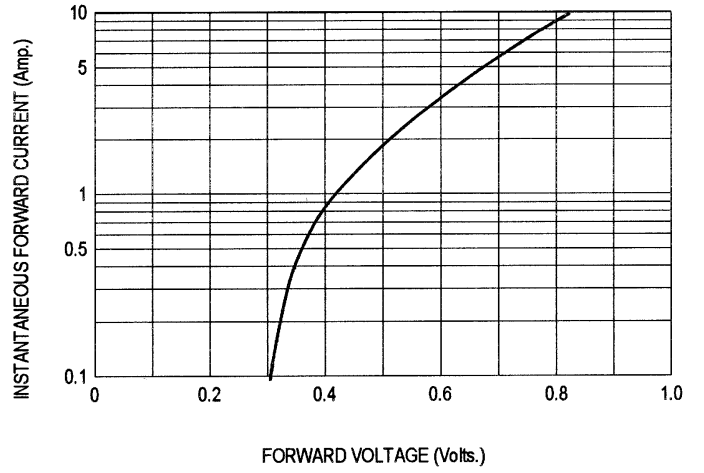


FIG-3 TYPICAL REVERSE CHARACTERISTICS

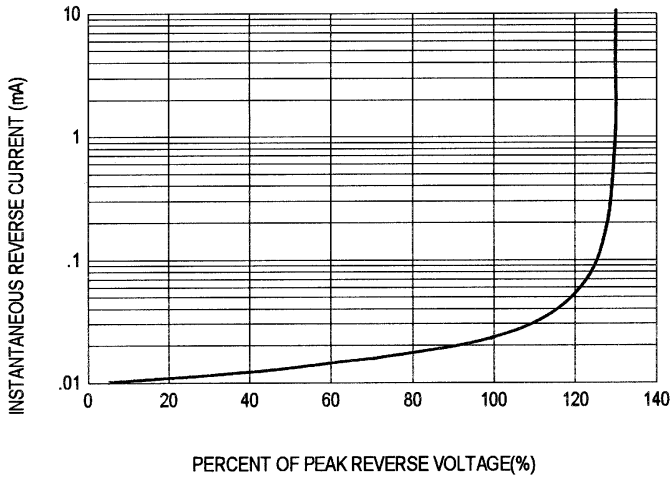


FIG-4 TYPICAL JUNCTION CAPACITANCE

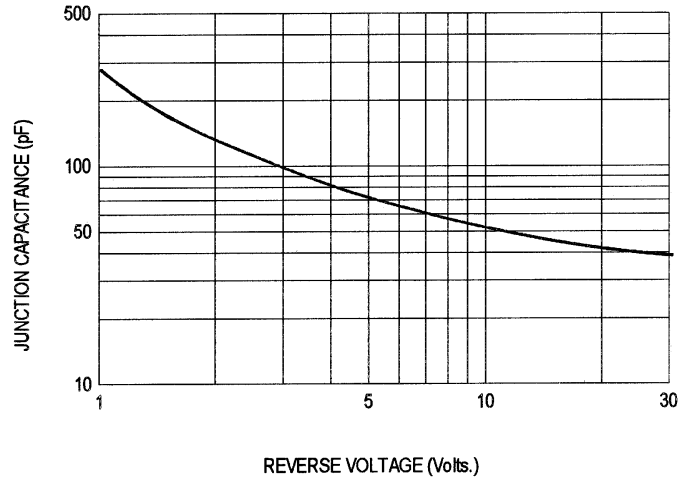
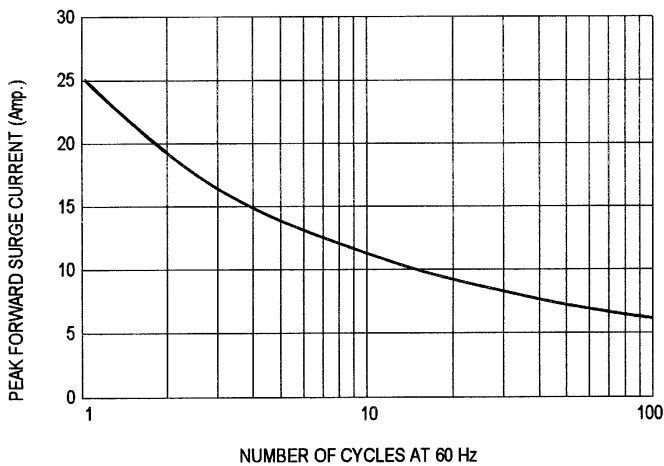


FIG-5 PEAK FORWARD SURGE CURRENT



# SM18, SM19

FIG-1 FORWARD CURRENT DERATING CURVE

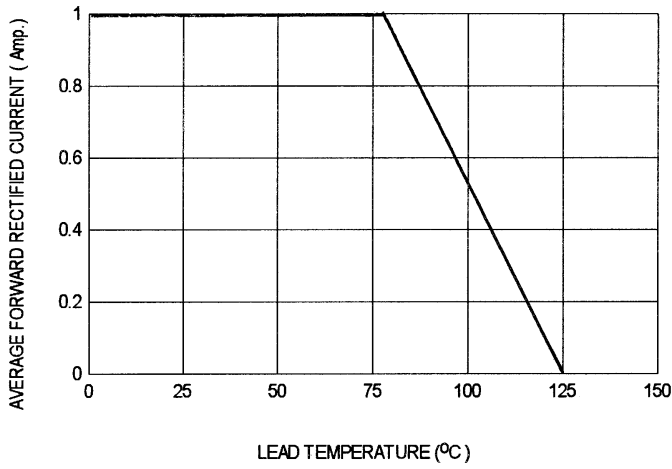


FIG-2 TYPICAL FORWARD CHARACTERISTICS

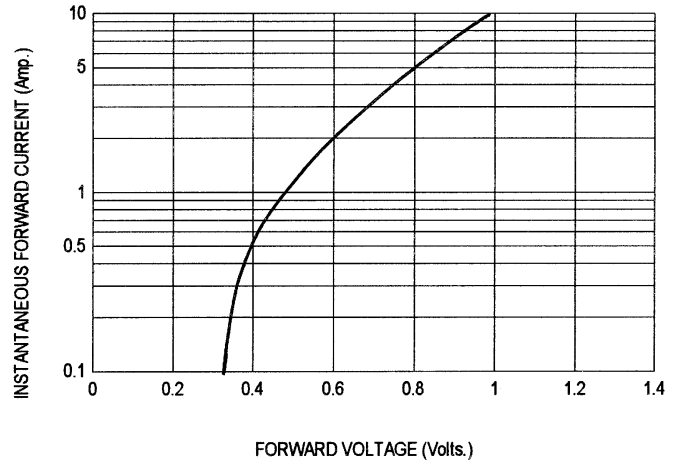


FIG-3 TYPICAL REVERSE CHARACTERISTICS

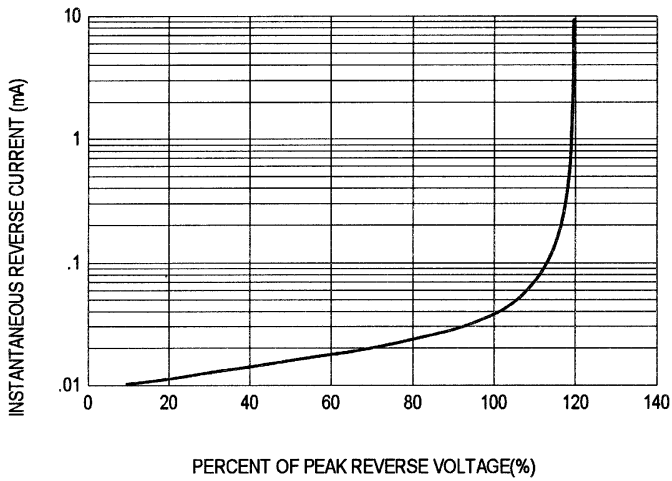


FIG-4 TYPICAL JUNCTION CAPACITANCE

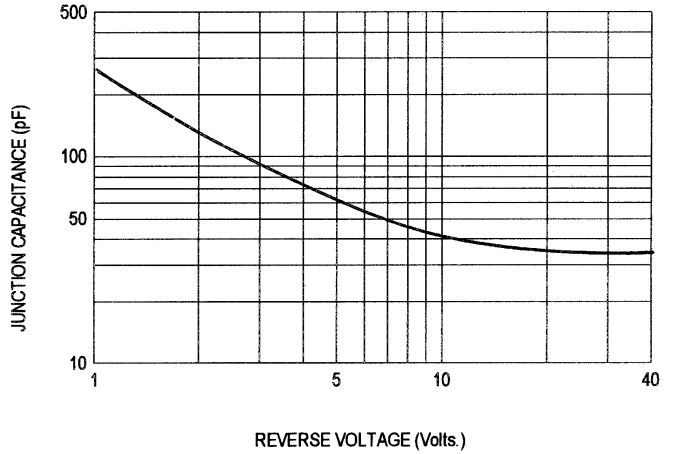


FIG-5 PEAK FORWARD SURGE CURRENT

